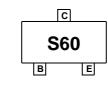


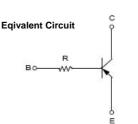
## **FJY4010R PNP Epitaxial Silicon Transistor**

## **Features**

- · Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=10KΩ)
- Complement to FJY3010R







## Absolute Maximum Ratings \* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	-40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-40	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-100	mA
T <sub>STG</sub>	Storage Temperature Range	-55~150	°C
TJ	Junction Temperature	150	°C
P <sub>C</sub>	Collector Power Dissipation, by $R_{\theta JA}$	200	mW

These ratings are limiting values above which the serviceability of any semiconductor device may by impaired.

#### Thermal Characteristics\* Ta=25°C unless otherwise noted

Symbol	Parameter	Мах	Units
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	600	°C/W

Minimum land pad size.

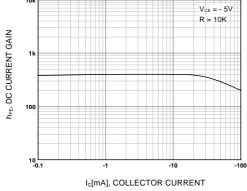
## Electrical Characteristics\* T<sub>c</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	MIN	Тур	MAX	Units
V(BR)CBO	Collector-Emitter Breakdown Voltage	Ic = -100 uA, IE = 0	-40			V
V(BR)CEO	Collector-Base Breakdown Voltage	Ic = -1mA, I <sub>B</sub> = 0	-40			V
Ісво	Collector-Cutoff Current	$V_{CB} = -30 V$ , $I_E = 0$			-0.1	uA
hfe	DC Current Gain	Vce = -5 V, Ic = -1 mA	100		600	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	Ic = -10 mA, I <sub>B</sub> = -1 mA			-0.3	V
f⊤	Current Gain - Bandwidth Product	Vce = -10V, lc =- 5 mA		200		MHz
Ccb	Output Capacitance	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1.0 MHz		5.5		pF
R	Input Resistor		7	10	13	KΩ

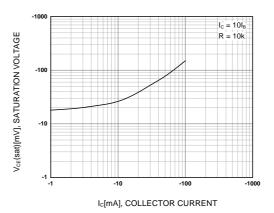
\* Pulse Test: PW≤300µs, Duty Cycle≤2%

November 2006

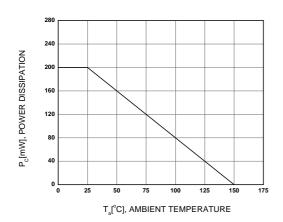
# Typical Performance Characteristics Figure 1. DC current Gain

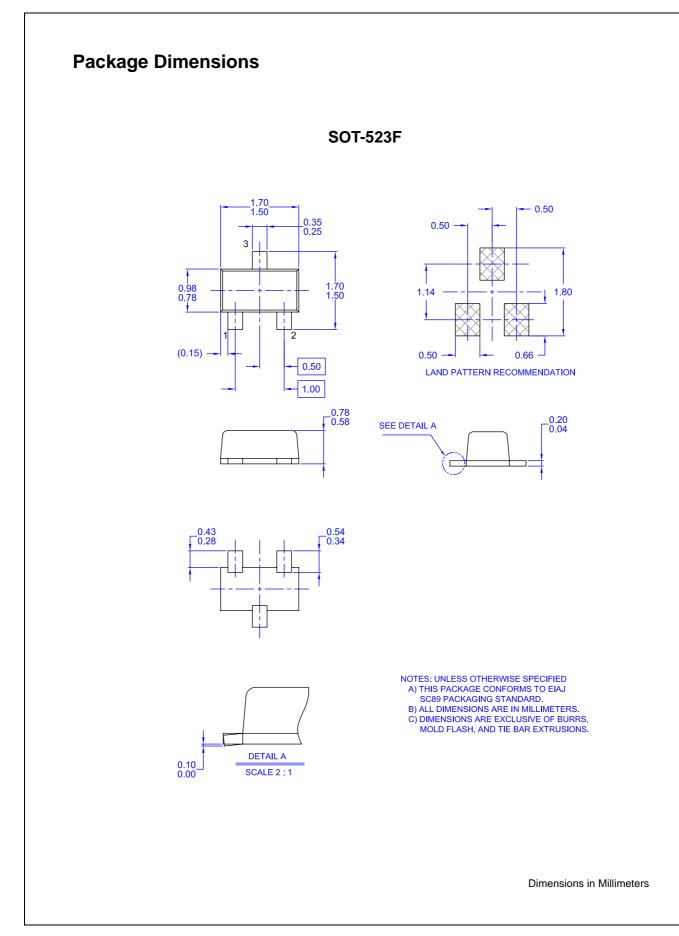


### Figure 2. Collector-Emitter Saturation Voltage



#### Figure 3. Power Derating







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Build it Now™	HiSeC™	OPTOPLANAR™	Stealth™	
CoolFET™	I <sup>2</sup> C™	PACMAN™	SuperFET™	
CROSSVOLT™	<i>i-Lo</i> ™	POP™	SuperSOT™-3	
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